

PATENT

U.S. UTILITY Patent Application

NS O.P.E.

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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/805273	D	438	786	28 282	Cotrada

APPLICANTS  
TITLE

Wenge Yang

Highly conductive semiconductor structures, method of forming same  
via plasma etch, and electrical devices incorporating highly  
conductive semiconductor structures

PTO-2040  
12/99